## ECE 656 Homework (Week 11) Mark Lundstrom Purdue University

1) Consider a semiconductor with a slowly varying effective mass,  $m^*(x)$ . Derive the equation of motion for an electron in *k*-space analogous to the result for a constant effective mass:

$$\frac{d(\hbar k_x)}{dt} = F_e = -\frac{dE_C(x)}{dx}.$$

2) Consider a semiconductor with a position dependent effective mass and electron affinity,  $\chi(x)$ , so that

$$E_{C}(x) = E_{vac} - \chi(x) - qV(x)$$

where  $E_{vac}$  is a constant, reference energy (the vacuum level) and V(x) is the electrostatic potential.

Solve the steady-state BTE in the relaxation time approximation and compare your result to the results for a constant effective mass and electron affinity:

$$J_{nx} = \sigma \frac{d(F_n/q)}{dx} - \sigma S \frac{dT}{dx}$$

3) Solve the steady-state BTE in the Relaxation Time Approximation and derive an expression for the transport tensor,  $[\kappa_0]_{ii}$  in the absence of a B-field.